20 V, 200 mA, Low Noise, CMOS LDO Linear Regulator

Data Sheet **ADP7112**

FEATURES

- Low noise: 11 µV rms independent of fixed output voltage
- PSRR of 88 dB at 10 kHz, 68 dB at 100 kHz, 50 dB at 1 MHz, V_{OUT} = 5 V, V_{IN} = 7 V
- Input voltage range: 2.7 V to 20 V
- Maximum output current: 200 mA
- Initial accuracy: ±0.8%
- Accuracy over line, load, and temperature ±1.8%, T_J = −40°C to +125°C
- Low dropout voltage: 200 mV (typical) at a 200 mA load, V_{OUT} = 5 V
- User-programmable soft start
- Low quiescent current, I_{GND} = 50 µA (typical) with no load
- Low shutdown current
  - 1.8 µA at V_{IN} = 5 V
  - 3.0 µA at V_{IN} = 20 V
  - Stable with a small 2.2 µF ceramic output capacitor
- Fixed output voltage options: 1.8 V, 2.5 V, 3.3 V, and 5.0 V
  - 15 standard voltages between 1.2 V and 5.0 V are available
- Adjustable output from 1.2 V to V_{IN} – V_{DO}, output can be adjusted above initial set point
- Precision enable
- 1 mm × 1.2 mm, 6-ball WLCSP

APPLICATIONS

- Regulation to noise sensitive applications
  - ADC and DAC circuits, precision amplifiers, power for VCO V_{TUNE} control
- Communications and infrastructure
- Medical and healthcare
- Industrial and instrumentation

TYPICAL APPLICATION CIRCUITS

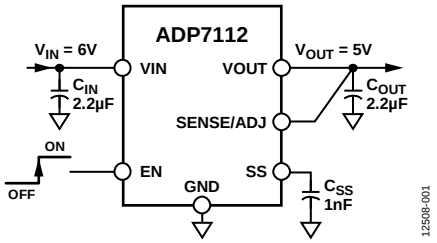

Figure 1. ADP7112 with Fixed Output Voltage, 5 V

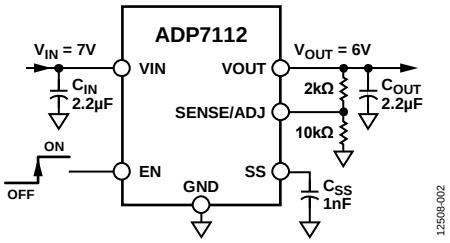

Figure 2. ADP7112 with 5 V Output Adjusted to 6 V

GENERAL DESCRIPTION

The ADP7112 is a CMOS, low dropout (LDO) linear regulator that operates from 2.7 V to 20 V and provides up to 200 mA of output current. This high input voltage LDO is ideal for the regulation of high performance analog and mixed-signal circuits operating from 20 V down to 1.2 V rails. Using an advanced proprietary architecture, the device provides high power supply rejection, low noise, and achieves excellent line and load transient response with a small 2.2 µF ceramic output capacitor. The ADP7112 regulator output noise is 11 µV rms, independent of the output voltage for the fixed options of 5 V or less.

The ADP7112 is available in 15 fixed output voltage options. The following voltages are available from stock: 1.2 V (adjustable), 1.8 V, 2.5 V, 3.3 V, and 5.0 V. Additional voltages available by special order are 1.5 V, 1.85 V, 2.0 V, 2.2 V, 2.75 V, 2.8 V, 2.85 V, 3.8 V, 4.2 V, and 4.6 V.

Each fixed output voltage can be adjusted above the initial set point with an external feedback divider. This allows the ADP7112 to provide an output voltage from 1.2 V to V_{IN} – V_{DO} with high PSRR and low noise.

A user-programmable soft start with an external capacitor is available in the ADP7112. The ADP7112 is available in a 6-ball 1 mm × 1.2 mm WLCSP, making it a very compact solution.

Rev. C

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
Tel: 781.329.4700
Technical Support www.analog.com

ADP7112* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS

View a parametric search of comparable parts.

EVALUATION KITS

- ADP7112 Evaluation Board

DOCUMENTATION

Data Sheet

- ADP7112:20 V, 200 mA, Low Noise, CMOS LDO Linear Regulator Data Sheet

User Guides

- UG-777: Evaluating the ADP7112 Low Noise, CMOS LDO Linear Regulator

TOOLS AND SIMULATIONS

- ADI Linear Regulator Design Tool and Parametric Search
- ADIsimPower™ Voltage Regulator Design Tool

REFERENCE MATERIALS

Solutions Bulletins & Brochures

- Ultralow Noise, High Rejection Low Dropout Regulators

DESIGN RESOURCES

- ADP7112 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all ADP7112 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK

Submit feedback for this data sheet.

TABLE OF CONTENTS

REVISION HISTORY

7/2016—Rev. B to Rev. C

Changes to Figure 40 ... 13
Changes to Programmable Precision Enable Section and Soft Start Section ... 15
Added Effect of Noise Reduction on Start-Up Time Section ... 16

12/2014—Rev. A to Rev. B

Changed EN to GND Parameter from −0.3 V to VIN to −0.3 V to +24 V, Table 3 ... 5

12/2014—Rev. 0 to Rev. A

Changes to Figure 34 to Figure 39 ... 12
Changes to Figure 42 ... 14

9/2014—Revision 0: Initial Version

SPECIFICATIONS

V_{IN} = V_{OUT} + 1 V or 2.7 V, whichever is greater, V_{OUT} = 5 V, EN = V_{IN}, I_{OUT} = 10 mA, C_{IN} = C_{OUT} = 2.2 µF, C_{SS} = 0 pF, T_A = 25°C for typical specifications, T_J = −40°C to +125°C for minimum/maximum specifications, unless otherwise noted.

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT VOLTAGE RANGE	V_{IN}		2.7		20	V
MAXIMUM OUTPUT CURRENT	I_{LOAD_MAX}			200		mA
OPERATING SUPPLY CURRENT	I_{GND}	I_{OUT} = 0 µA		50	140	µA
		I_{OUT} = 10 mA		80	190	µA
		I_{OUT} = 200 mA		180	320	µA
SHUTDOWN CURRENT	I_{GND-SD}	EN = GND		1.8		µA
		EN = GND, V_{IN} = 20 V		3.0		µA
		EN = GND			10	µA
OUTPUT VOLTAGE ACCURACY						
Output Voltage Accuracy	V_{OUT}	I_{OUT} = 10 mA, T_J = 25°C	−0.8		+0.8	%
		100 µA < I_{OUT} < 200 mA, V_{IN} = (V_{OUT} + 1 V) to 20 V	−1.8		+1.8	%
LINE REGULATION	$\Delta V_{OUT}/\Delta V_{IN}$	V_{IN} = (V_{OUT} + 1 V) to 20 V	−0.02		+0.02	%/V
LOAD REGULATION[1]	$\Delta V_{OUT}/\Delta I_{OUT}$	I_{OUT} = 100 µA to 200 mA		0.002	0.004	%/mA
SENSE INPUT BIAS CURRENT	$SENSE_{I-BIAS}$	100 µA < I_{OUT} < 200 mA V_{IN} = (V_{OUT} + 1 V) to 20 V		10	1000	nA
DROPOUT VOLTAGE[2]	$V_{DROPOUT}$	I_{OUT} = 10 mA		30	60	mV
		I_{OUT} = 200 mA		200	420	mV
START-UP TIME[3]	$T_{START-UP}$	V_{OUT} = 5 V		380		µs
SOFT START SOURCE CURRENT	$SS_{I-SOURCE}$	SS = GND		1.15		µA
CURRENT-LIMIT THRESHOLD[4]	I_{LIMIT}		250	360	460	mA
THERMAL SHUTDOWN						
Thermal Shutdown Threshold	TS_{SD}	T_J rising		150		°C
Thermal Shutdown Hysteresis	TS_{SD-HYS}			15		°C
UNDERVOLTAGE THRESHOLDS						
Input Voltage Rising	$UVLO_{RISE}$				2.69	V
Input Voltage Falling	$UVLO_{FALL}$		2.2			V
Hysteresis	$UVLO_{HYS}$			230		mV
EN INPUT STANDBY		2.7 V ≤ V_{IN} ≤ 20 V				
EN Input Logic High	$EN_{STBY-HIGH}$		1.0			V
EN Input Logic Low	$EN_{STBY-LOW}$				0.4	V
EN Input Logic Hysteresis	$EN_{STBY-HYS}$			150		mV
EN INPUT PRECISION		2.7 V ≤ V_{IN} ≤ 20 V				
EN Input Logic High	EN_{HIGH}		1.15	1.22	1.30	V
EN Input Logic Low	EN_{LOW}		1.06	1.12	1.18	V
EN Input Logic Hysteresis	EN_{HYS}			100		mV
EN Input Leakage Current	I_{EN-LKG}	EN = V_{IN} or GND		0.04	1	µA
EN Input Delay Time	t_{EN-DLY}	From EN rising from 0 V to V_{IN} to 0.1 × V_{OUT}		80		µs
OUTPUT NOISE	OUT_{NOISE}	10 Hz to 100 kHz, all output voltage options		11		µV rms
POWER SUPPLY REJECTION RATIO	PSRR	1 MHz, V_{IN} = 7 V, V_{OUT} = 5 V		50		dB
		100 kHz, V_{IN} = 7 V, V_{OUT} = 5 V		68		dB
		10 kHz, V_{IN} = 7 V, V_{OUT} = 5 V		88		dB

[1] Based on an endpoint calculation using 100 µA and 200 mA loads. See Figure 5 for typical load regulation performance for loads less than 1 mA.
[2] Dropout voltage is defined as the input-to-output voltage differential when the input voltage is set to the nominal output voltage. Dropout applies only for output voltages greater than 2.7 V.
[3] Start-up time is defined as the time between the rising edge of EN to VOUT being at 90% of its nominal value.
[4] Current-limit threshold is defined as the current at which the output voltage drops to 90% of the specified typical value. For example, the current limit for a 5.0 V output voltage is defined as the current that causes the output voltage to drop to 90% of 5.0 V or 4.5 V.

INPUT AND OUTPUT CAPACITANCE, RECOMMENDED SPECIFICATIONS

Table 2.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT AND OUTPUT CAPACITANCE						
Minimum Capacitance[1]	C_{MIN}	T_A = −40°C to +125°C	1.5			µF
Capacitor Effective Series Resistance (ESR)	R_{ESR}	T_A = −40°C to +125°C	0.001		0.3	Ω

[1] The minimum input and output capacitance must be greater than 1.5 µF over the full range of operating conditions. The full range of operating conditions in the application must be considered during device selection to ensure that the minimum capacitance specification is met. X7R and X5R type capacitors are recommended, whereas Y5V and Z5U capacitors are not recommended for use with any LDO.

ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
VIN to GND	−0.3 V to +24 V
VOUT to GND	−0.3 V to VIN
EN to GND	−0.3 V to +24 V
SENSE/ADJ to GND	−0.3 V to +6 V
SS to GND	−0.3 V to VIN or +6 V (whichever is less)
Storage Temperature Range	−65°C to +150°C
Operating Junction Temperature (T_J) Range	−40°C to +125°C
Operating Ambient Temperature (T_A) Range	−40°C to +85°C
Soldering Conditions	JEDEC J-STD-020

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL DATA

Absolute maximum ratings apply individually only, not in combination. The ADP7112 can be damaged when the junction temperature limits are exceeded. Monitoring ambient temperature does not guarantee that T_J is within the specified temperature limits. In applications with high power dissipation and poor thermal resistance, the maximum ambient temperature can have to be derated.

In applications with moderate power dissipation and low printed circuit board (PCB) thermal resistance, the maximum ambient temperature can exceed the maximum limit as long as the junction temperature is within specification limits. The junction temperature of the device is dependent on the ambient temperature, the power dissipation (P_D) of the device, and the junction-to-ambient thermal resistance of the package (θ_{JA}).

Maximum T_J is calculated from the T_A and P_D using the formula

$$T_J = T_A + (P_D \times \theta_{JA}) \quad (1)$$

θ_{JA} of the package is based on modeling and calculation using a 4-layer board. The θ_{JA} is highly dependent on the application and board layout. In applications where high maximum power dissipation exists, close attention to thermal board design is required. The value of θ_{JA} can vary, depending on PCB material, layout, and environmental conditions. The specified values of θ_{JA} are based on a 4-layer, 4 in. × 3 in. circuit board. See JESD51-7 and JESD51-9 for detailed information on the board construction.

Ψ_{JB} is the junction-to-board thermal characterization parameter with units of °C/W. The Ψ_{JB} of the package is based on modeling and calculation using a 4-layer board. The JESD51-12, *Guidelines for Reporting and Using Electronic Package Thermal Information*, states that thermal characterization parameters are not the same as thermal resistances. Ψ_{JB} measures the component power flowing through multiple thermal paths rather than a single path as in thermal resistance (θ_{JB}). Therefore, Ψ_{JB} thermal paths include convection from the top of the package as well as radiation from the package, factors that make Ψ_{JB} more useful in real-world applications. Maximum T_J is calculated from the board temperature (T_B) and P_D using the formula

$$T_J = T_B + (P_D \times \Psi_{JB}) \quad (2)$$

See JESD51-8 and JESD51-12 for more detailed information about Ψ_{JB}.

THERMAL RESISTANCE

θ_{JA}, θ_{JC}, and Ψ_{JB} are specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 4. Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Ψ_{JB}	Unit
6-Ball WLCSP	260	4	58	°C/W

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

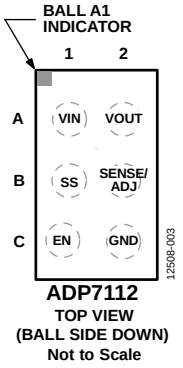

Figure 3. Pin Configuration

Table 5. Pin Function Descriptions

Pin	Mnemonic	Description
A1	VIN	Regulator Input Supply. Bypass VIN to GND with a 2.2 µF or greater capacitor.
B1	SS	Soft Start. An external capacitor connected to this pin determines the soft start time. Leave this pin open for a typical 380 µs start-up time. Do not ground this pin.
C1	EN	The enable pin controls the operation of the LDO. Drive EN high to turn on the regulator. Drive EN low to turn off the regulator. For automatic startup, connect EN to VIN.
A2	VOUT	Regulated Output Voltage. Bypass VOUT to GND with a 2.2 µF or greater capacitor.
B2	SENSE/ADJ	Sense Input (SENSE). Connect to load. Adjustable Model (ADJ). The adjustable model has a fixed output set to 1.2 V. The output can be set to a voltage higher than 1.2 V by connecting an external resistor divider to the ADJ pin.
C2	GND	Ground.

TYPICAL PERFORMANCE CHARACTERISTICS

V_{IN} = V_{OUT} + 1 V or 2.7 V, whichever is greater, V_{OUT} = 5 V, I_{LOAD} = 10 mA, C_{IN} = C_{OUT} = 2.2 µF, T_A = 25°C, unless otherwise noted.

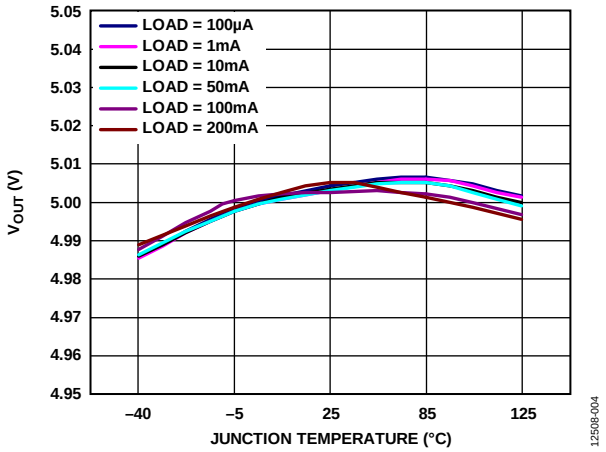

Figure 4. Output Voltage (V_{OUT}) vs. Junction Temperature

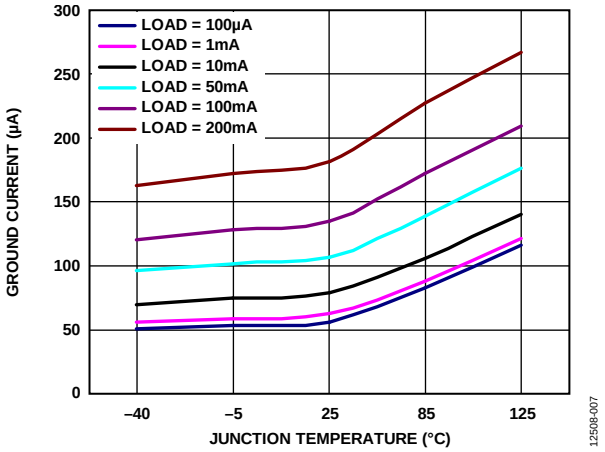

Figure 7. Ground Current vs. Junction Temperature

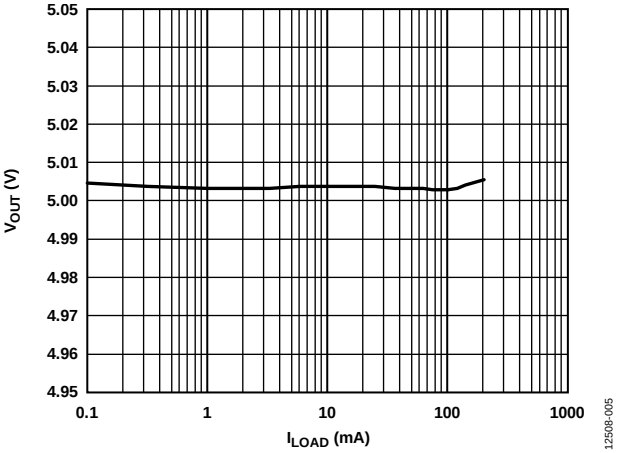

Figure 5. Output Voltage (V_{OUT}) vs. Load Current (I_{LOAD})

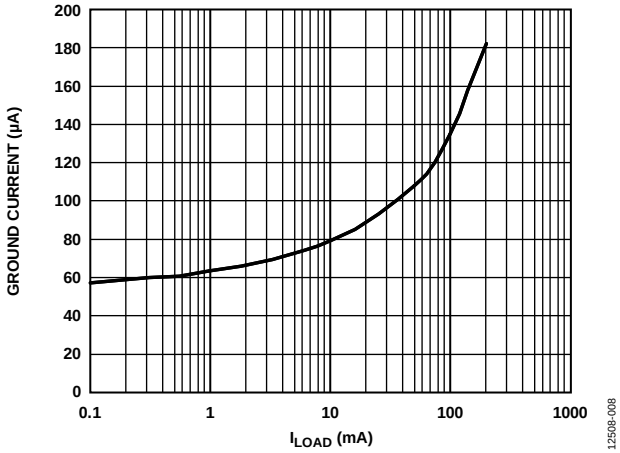

Figure 8. Ground Current vs. Load Current (I_{LOAD})

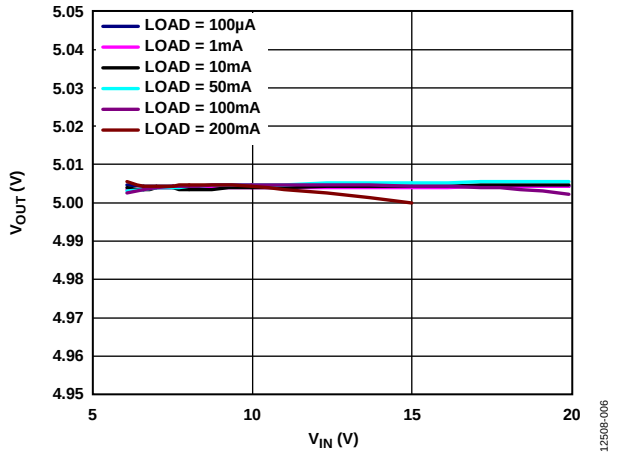

Figure 6. Output Voltage (V_{OUT}) vs. Input Voltage (V_{IN})

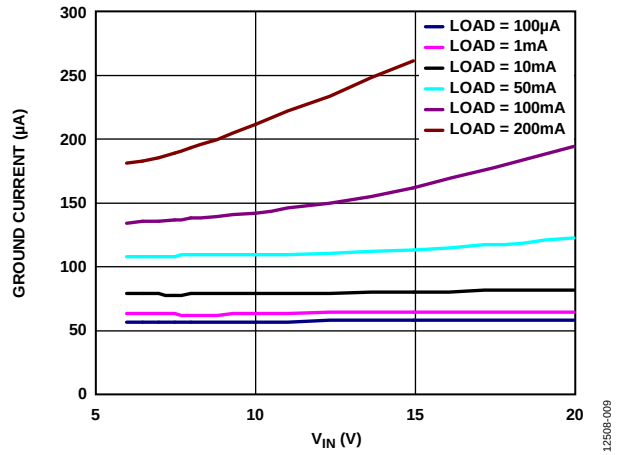

Figure 9. Ground Current vs. Input Voltage (V_{IN})

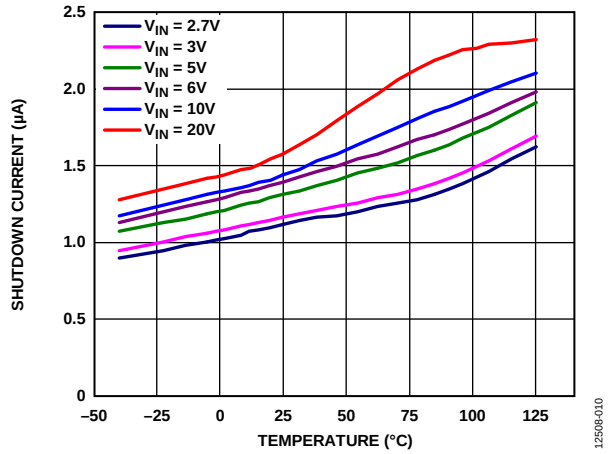

Figure 10. Shutdown Current vs. Temperature at Various Input Voltages

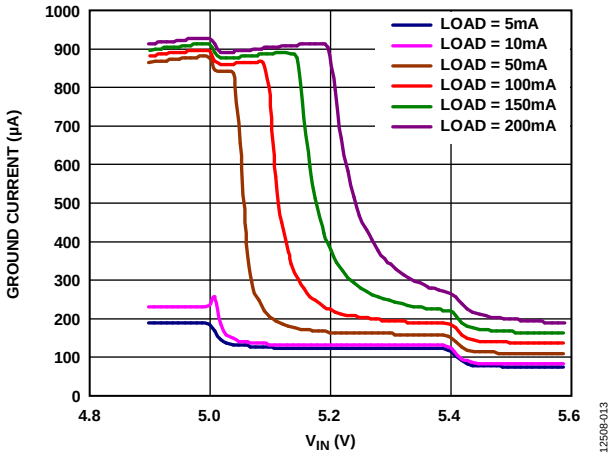

Figure 13. Ground Current vs. Input Voltage (V_{IN}) in Dropout, V_{OUT} = 5 V

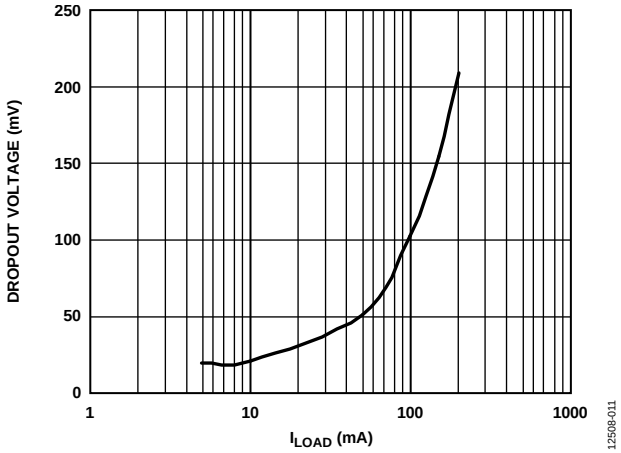

Figure 11. Dropout Voltage vs. Load Current (I_{LOAD}), V_{OUT} = 5 V

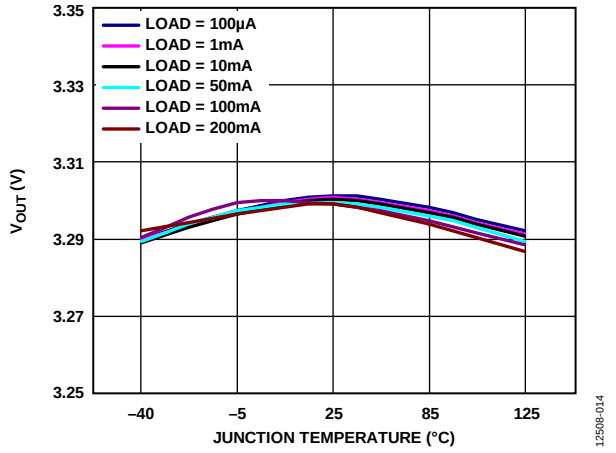

Figure 14. Output Voltage (V_{OUT}) vs. Junction Temperature, V_{OUT} = 3.3 V

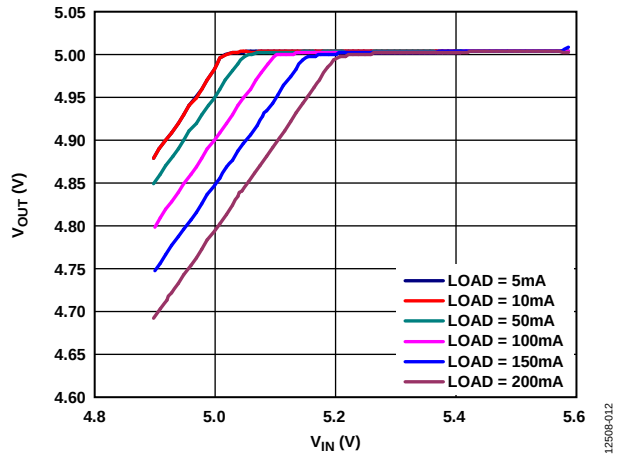

Figure 12. Output Voltage (V_{OUT}) vs. Input Voltage (V_{IN}) in Dropout, V_{OUT} = 5 V

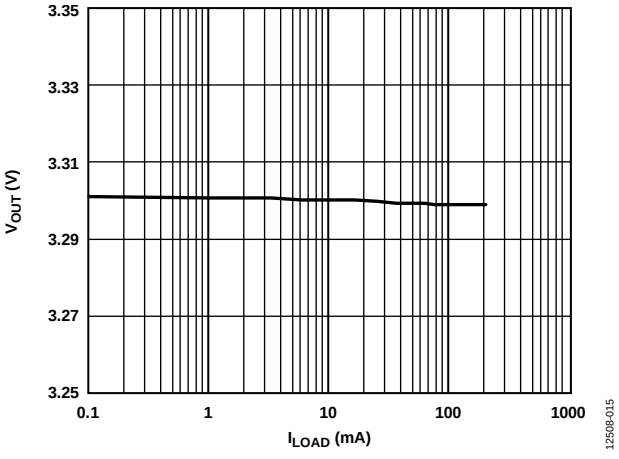

Figure 15. Output Voltage (V_{OUT}) vs. Load Current (I_{LOAD}), V_{OUT} = 3.3 V

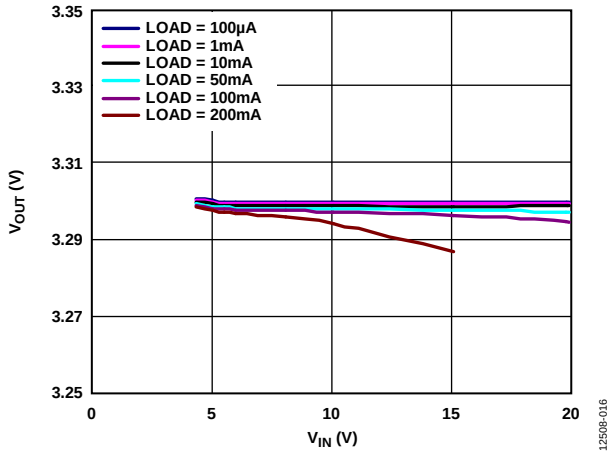

Figure 16. Output Voltage (V_{OUT}) vs. Input Voltage (V_{IN}), V_{OUT} = 3.3 V

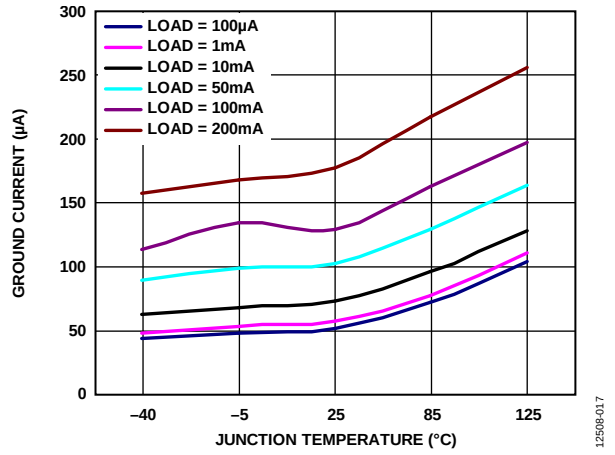

Figure 17. Ground Current vs. Junction Temperature, V_{OUT} = 3.3 V

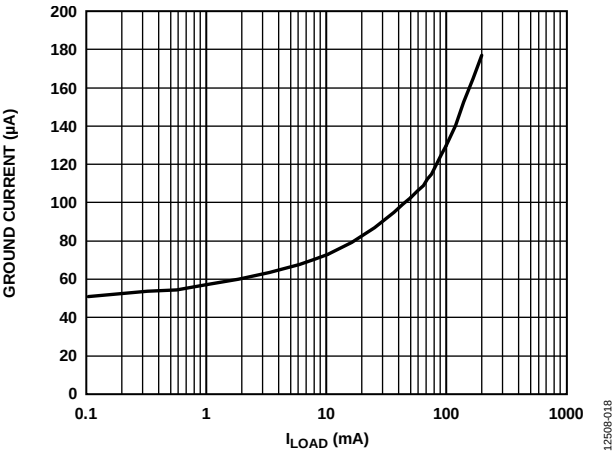

Figure 18. Ground Current vs. Load Current (I_{LOAD}), V_{OUT} = 3.3 V

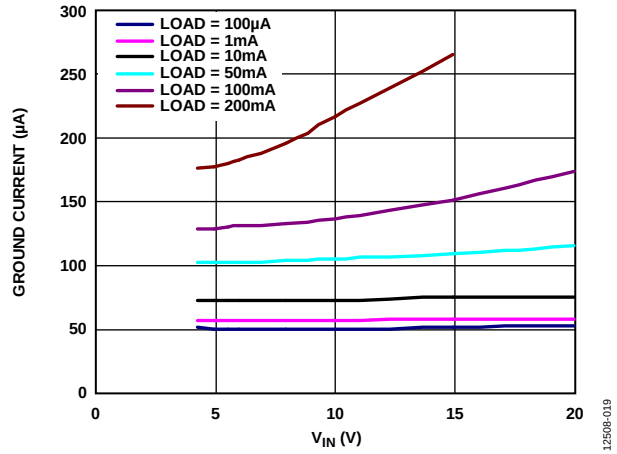

Figure 19. Ground Current vs. Input Voltage (V_{IN}), V_{OUT} = 3.3 V

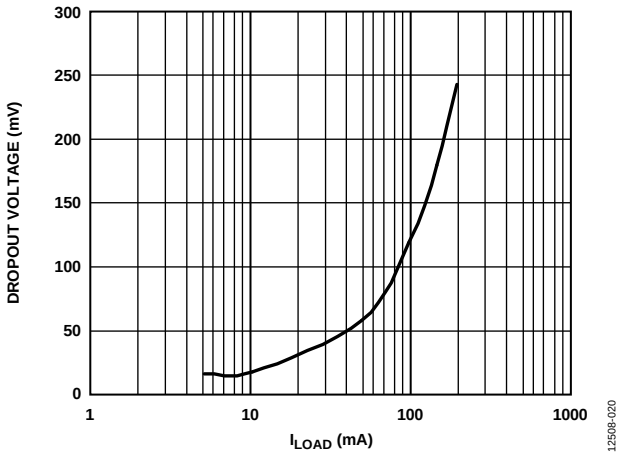

Figure 20. Dropout Voltage vs. Load Current (I_{LOAD}), V_{OUT} = 3.3 V

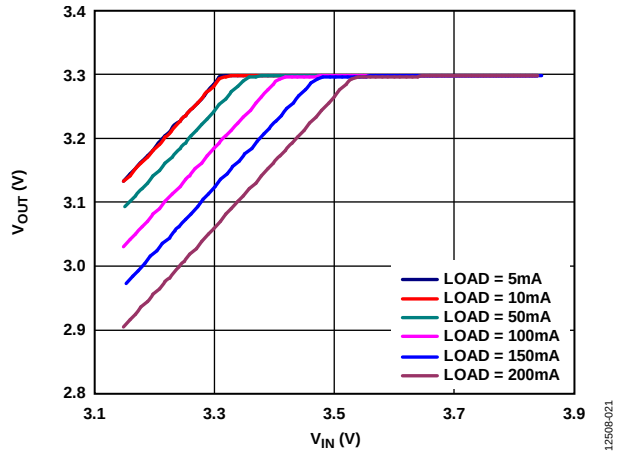

Figure 21. Output Voltage (V_{OUT}) vs. Input Voltage (V_{IN}) in Dropout, V_{OUT} = 3.3 V

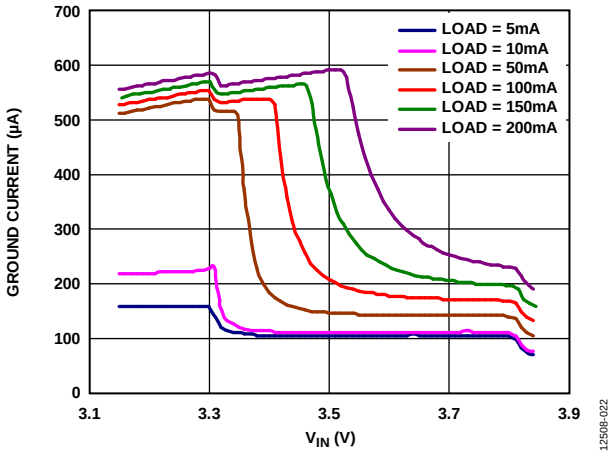

Figure 22. Ground Current vs. Input Voltage (V_{IN}) in Dropout, V_{OUT} = 3.3 V

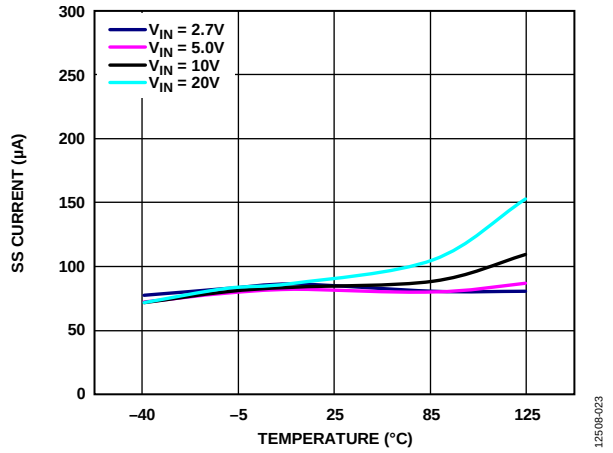

Figure 23. Soft Start (SS) Current vs. Temperature, Multiple Input Voltages, V_{OUT} = 5 V

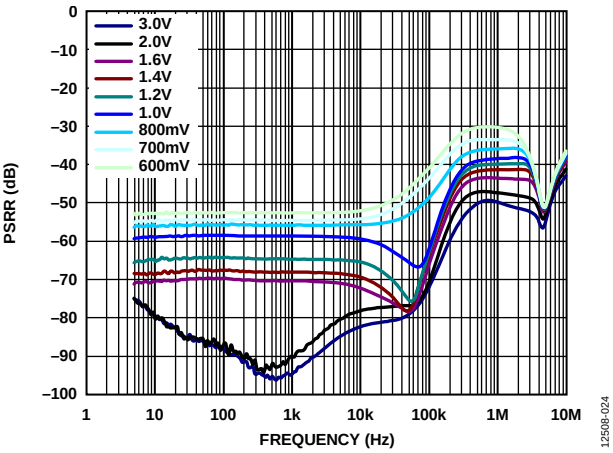

Figure 24. Power Supply Rejection Ratio (PSRR) vs. Frequency, V_{OUT} = 1.8 V, for Various Headroom Voltages

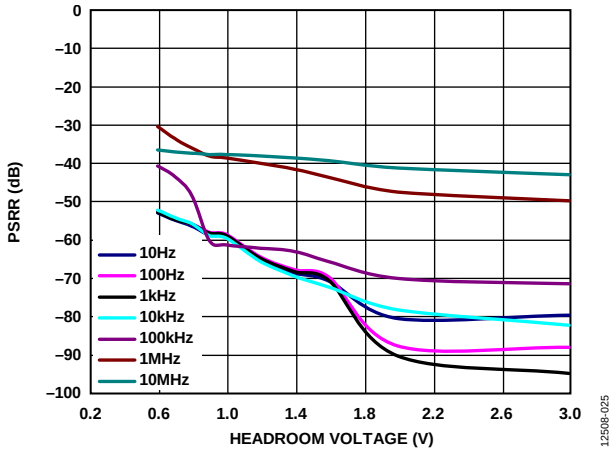

Figure 25. Power Supply Rejection Ratio (PSRR) vs. Headroom Voltage, V_{OUT} = 1.8 V, for Different Frequencies

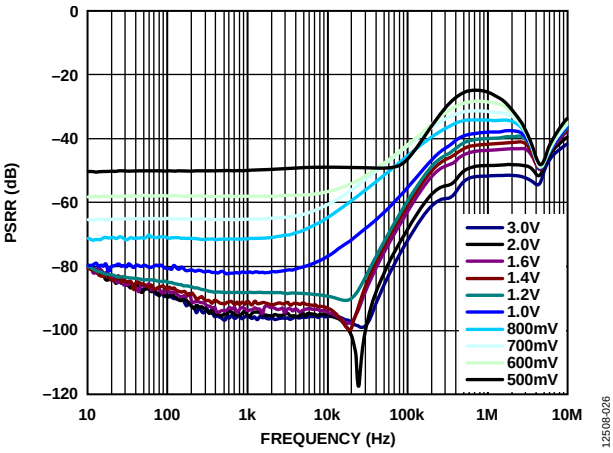

Figure 26. Power Supply Rejection Ratio (PSRR) vs. Frequency, V_{OUT} = 3.3 V, for Various Headroom Voltages

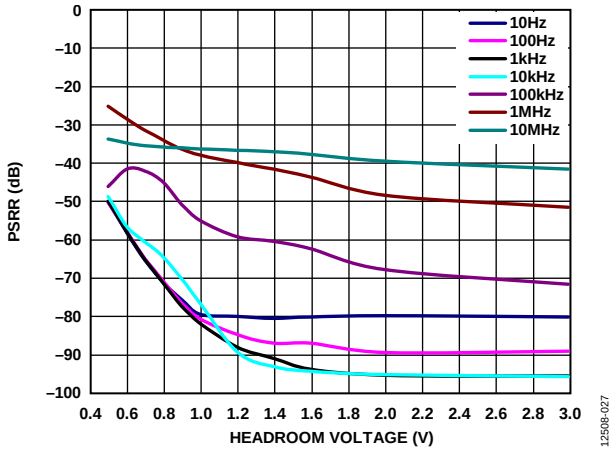

Figure 27. Power Supply Rejection Ratio (PSRR) vs. Headroom Voltage, V_{OUT} = 3.3 V, for Different Frequencies

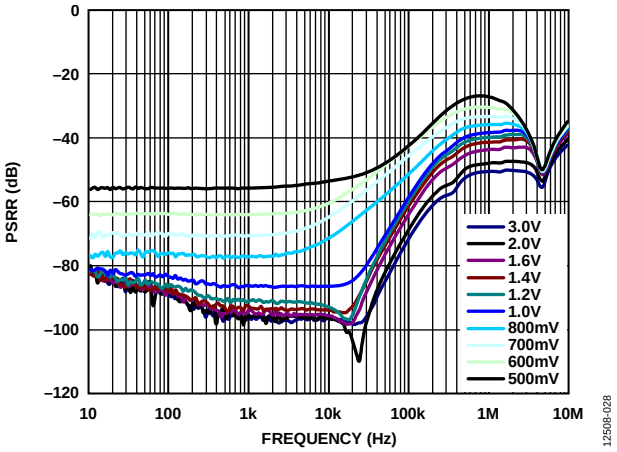

Figure 28. Power Supply Rejection Ratio (PSRR) vs. Frequency, V_{OUT} = 5 V, for Various Headroom Voltages

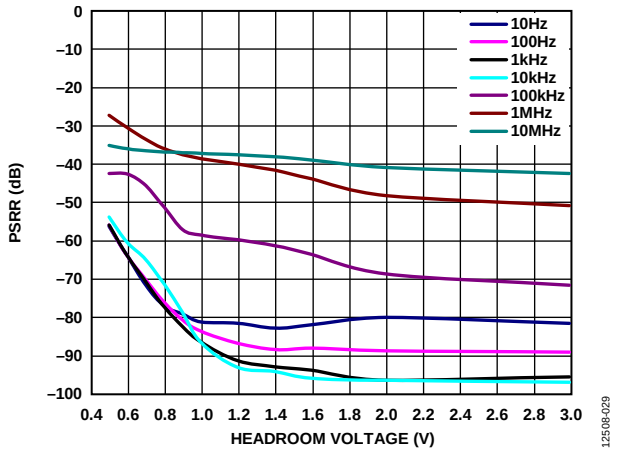

Figure 29. Power Supply Rejection Ratio (PSRR) vs. Headroom Voltage, V_{OUT} = 5 V, for Different Frequencies

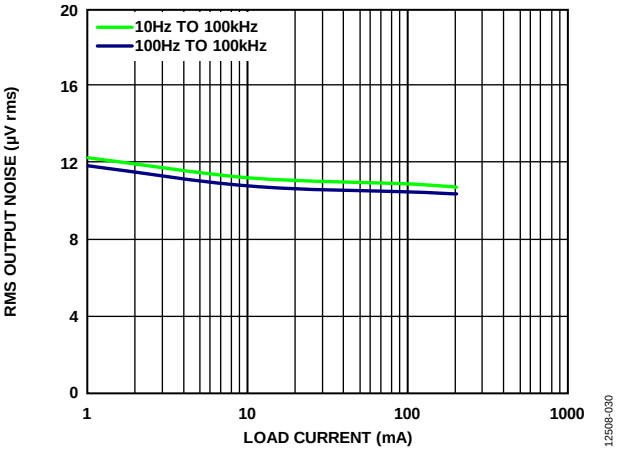

Figure 30. RMS Output Noise vs. Load Current

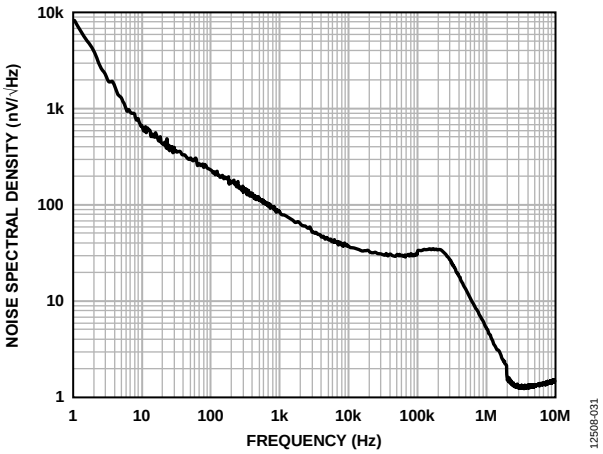

Figure 31. Output Noise Spectral Density vs. Frequency, I_{LOAD} = 10 mA

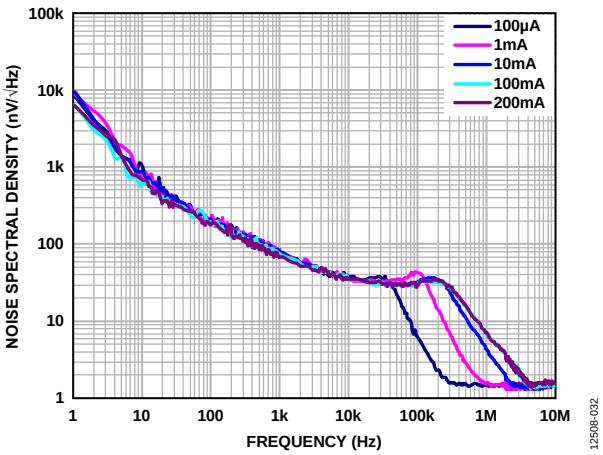

Figure 32. Output Noise Spectral Density vs. Frequency, for Different Loads

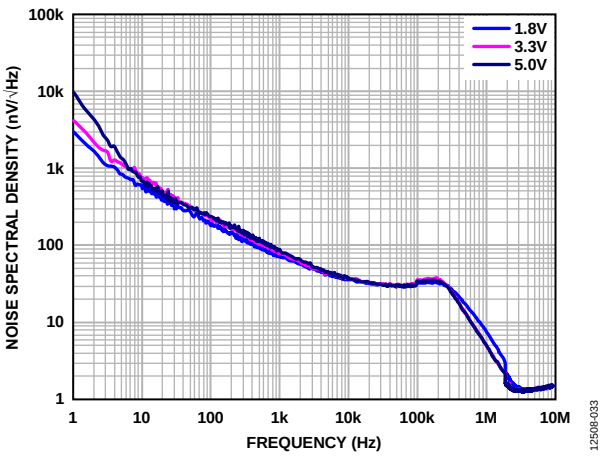

Figure 33. Output Noise Spectral Density vs. Frequency, for Different Output Voltages

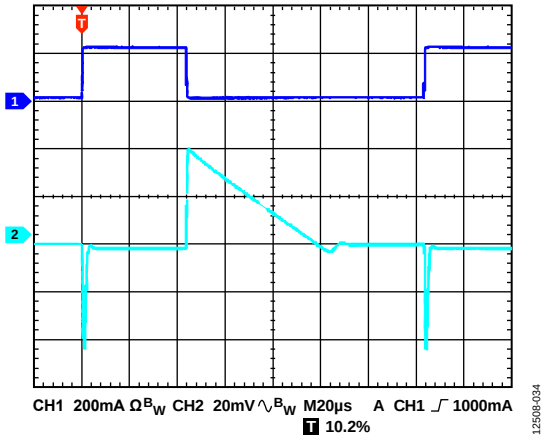

Figure 34. Load Transient Response, I_{LOAD} = 1 mA to 200 mA, V_{OUT} = 5 V, V_{IN} = 7 V, CH1 Load Current, CH2 V_{OUT}

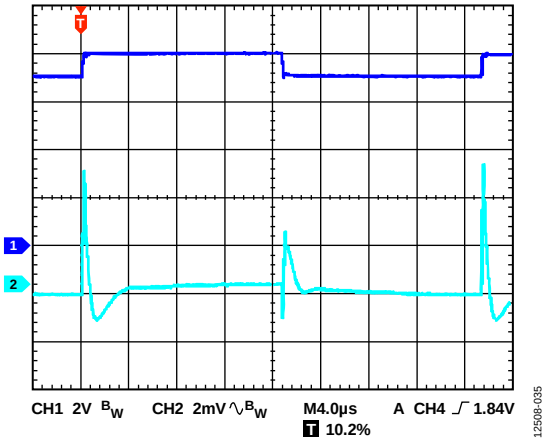

Figure 35. Line Transient Response, I_{LOAD} = 200 mA, V_{OUT} = 5 V, CH1 V_{IN}, CH2 V_{OUT}

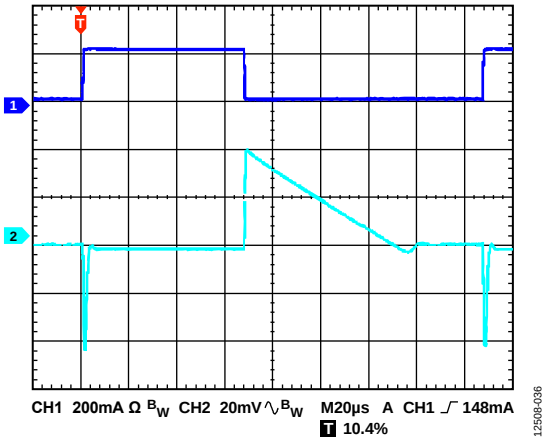

Figure 36. Load Transient Response, I_{LOAD} = 1 mA to 200 mA, V_{OUT} = 3.3 V, V_{IN} = 5 V, CH1 Load Current, CH2 V_{OUT}

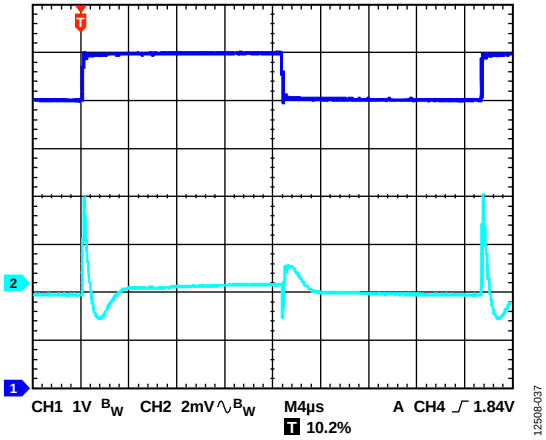

Figure 37. Line Transient Response, I_{LOAD} = 200 mA, V_{OUT} = 3.3 V, CH1 V_{IN}, CH2 V_{OUT}

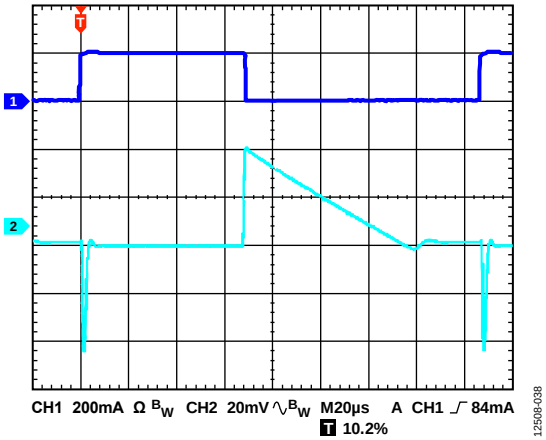

Figure 38. Load Transient Response, I_{LOAD} = 1 mA to 200 mA, V_{OUT} = 1.8 V, V_{IN} = 3 V, CH1 Load Current, CH2 V_{OUT}

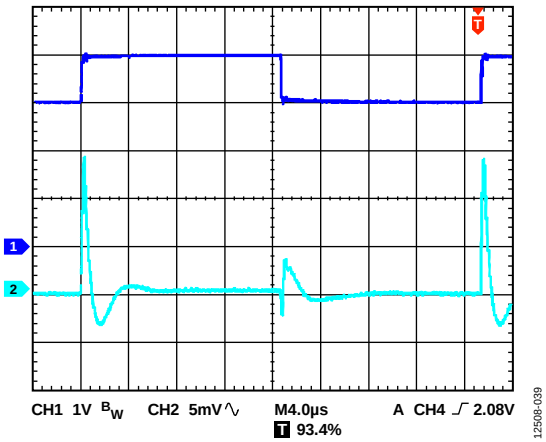

Figure 39. Line Transient Response, I_{LOAD} = 200 mA, V_{OUT} = 1.8 V, CH1 V_{IN}, CH2 V_{OUT}

THEORY OF OPERATION

The ADP7112 is a low quiescent current, LDO linear regulator that operates from 2.7 V to 20 V and provides up to 200 mA of output current. Drawing a low 180 µA of quiescent current (typical) at full load makes the ADP7112 ideal for portable equipment. Typical shutdown current consumption is around 3.0 µA at room temperature.

Optimized for use with small 2.2 µF ceramic capacitors, the ADP7112 provides excellent transient performance.

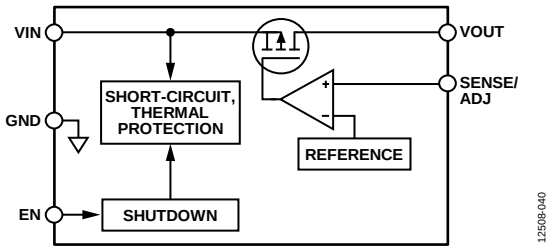

Figure 40. Internal Block Diagram

Internally, the ADP7112 consists of a reference, an error amplifier, a feedback voltage divider, and a PMOS pass transistor. Output current is delivered via the PMOS pass device, which is controlled by the error amplifier. The error amplifier compares the reference voltage with the feedback voltage from the output and amplifies the difference. If the feedback voltage is lower than the reference voltage, the gate of the PMOS device is pulled lower, allowing more current to pass and increasing the output voltage. If the feedback voltage is higher than the reference voltage, the gate of the PMOS device is pulled higher, allowing less current to pass and decreasing the output voltage.

The ADP7112 is available in 15 fixed output voltage options, ranging from 1.2 V to 5.0 V. The ADP7112 architecture allows any fixed output voltage to be set to a higher voltage with an external voltage divider. For example, a fixed 5 V output can be set to a 6 V output according to the following equation:

$$V_{OUT} = 5\ V(1 + R1/R2) \quad (3)$$

where R1 and R2 are the resistors in the output voltage divider shown in Figure 41.

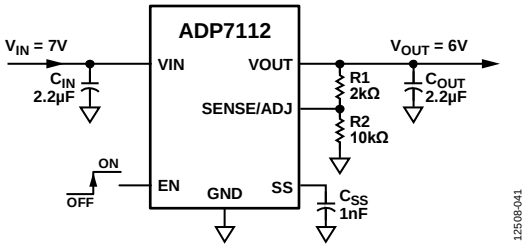

Figure 41. Typical Adjustable Output Voltage Application Schematic

It is recommended that the R2 value be less than 200 kΩ to minimize errors in the output voltage caused by the SENSE/ADJ pin input current. For example, when R1 and R2 each equal 200 kΩ and the default output voltage is 1.2 V, the adjusted output voltage is 2.4 V. The output voltage error introduced by the SENSE/ADJ pin input current is 1 mV or 0.04%, assuming a typical SENSE/ADJ pin input current of 10 nA at 25°C.

The ADP7112 uses the EN pin to enable and disable the VOUT pin under normal operating conditions. When EN is high, VOUT turns on, and when EN is low, VOUT turns off. For automatic startup, tie EN to VIN.

APPLICATIONS INFORMATION

CAPACITOR SELECTION

Output Capacitor

The ADP7112 is designed for operation with small, space-saving ceramic capacitors, but functions with general-purpose capacitors as long as care is taken with regard to the effective series resistance (ESR) value. The ESR of the output capacitor affects the stability of the LDO control loop. A 2.2 µF capacitance with an ESR of 0.3 Ω or less is recommended to ensure the stability of the ADP7112. Transient response to changes in load current is also affected by output capacitance. Using a larger value of output capacitance improves the transient response of the ADP7112 to large changes in load current. Figure 42 shows the transient responses for an output capacitance value of 2.2 µF.

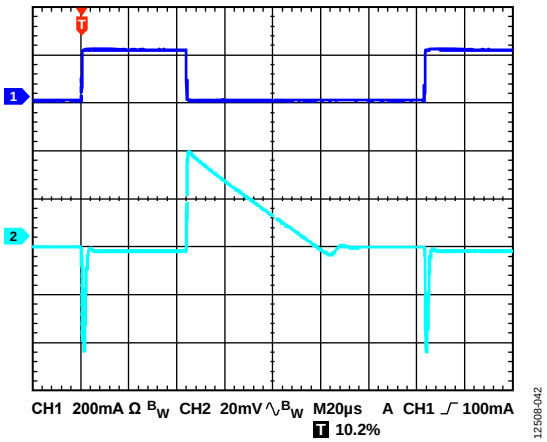

Figure 42. Output Transient Response, V_{OUT} = 5 V, C_{OUT} = 2.2 µF, CH1 Load Current, CH2 V_{OUT}

Input Bypass Capacitor

Connecting a 2.2 µF capacitor from VIN to GND reduces the circuit sensitivity to the PCB layout, especially when long input traces or high source impedance is encountered. If greater than 2.2 µF of output capacitance is required, increase the input capacitor to match it.

Input and Output Capacitor Properties

Any good quality ceramic capacitors can be used with the ADP7112, as long as they meet the minimum capacitance and maximum ESR requirements. Ceramic capacitors are manufactured with a variety of dielectrics, each with different behavior over temperature and applied voltage. Capacitors must have a dielectric adequate to ensure the minimum capacitance over the necessary temperature range and dc bias conditions. X5R or X7R dielectrics with a voltage rating of 6.3 V to 100 V are recommended. Y5V and Z5U dielectrics are not recommended, due to their poor temperature and dc bias characteristics.

Figure 43 depicts the capacitance vs. voltage bias characteristic of a 0805, 2.2 µF, 10 V, X5R capacitor. The voltage stability of a capacitor is strongly influenced by the capacitor size and voltage rating. In general, a capacitor in a larger package or higher voltage rating exhibits better stability. The temperature variation of the X5R dielectric is ~±15% over the −40°C to +85°C temperature range and is not a function of package or voltage rating.

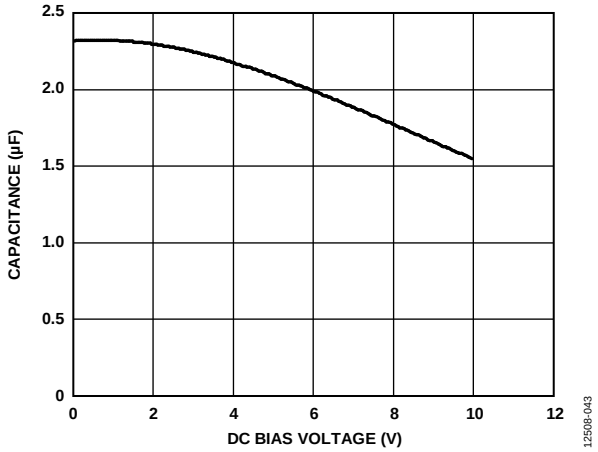

Figure 43. Capacitance vs. Voltage Characteristic

Use Equation 1 to determine the worst-case capacitance accounting for capacitor variation over temperature, component tolerance, and voltage.

$$C_{EFF} = C_{BIAS} \times (1 - TEMPCO) \times (1 - TOL) \quad (4)$$

where:

C_{BIAS} is the effective capacitance at the operating voltage.
TEMPCO is the worst-case capacitor temperature coefficient.
TOL is the worst-case component tolerance.

In this example, the worst-case temperature coefficient (TEMPCO) over −40°C to +85°C is assumed to be 15% for an X5R dielectric. The tolerance of the capacitor (TOL) is assumed to be 10%, and C_{BIAS} is 2.09 µF at 5 V, as shown in Figure 43.

These values in Equation 1 yield

$$C_{EFF} = 2.09\ \mu F \times (1 - 0.15) \times (1 - 0.1) = 1.59\ \mu F \quad (5)$$

Therefore, the capacitor chosen in this example meets the minimum capacitance requirement of the LDO over temperature and tolerance at the chosen output voltage.

To guarantee the performance of the ADP7112, it is imperative that the effects of dc bias, temperature, and tolerances on the behavior of the capacitors be evaluated for each application.

PROGRAMABLE PRECISION ENABLE

The ADP7112 uses the EN pin to enable and disable the VOUT pin under normal operating conditions. As shown in Figure 44, when a rising voltage on EN crosses the upper threshold, nominally 1.2 V, VOUT turns on. When a falling voltage on EN crosses the lower threshold, nominally 1.1 V, VOUT turns off. The hysteresis of the EN threshold is typically 100 mV.

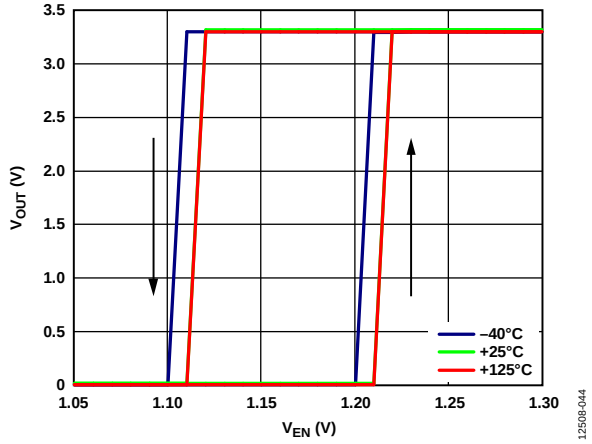

Figure 44. Typical V_{OUT} Response to EN Pin Operation

The upper and lower thresholds are user programmable and can be set higher than the nominal 1.2 V threshold by using two resistors. The resistance values, R_{EN1} and R_{EN2}, can be determined from

$$R_{EN2} = \text{nominally 10 k}\Omega \text{ to 100 k}\Omega \quad (6)$$

$$R_{EN1} = R_{EN2} \times (V_{IN} - 1.2\text{ V})/1.2\text{ V} \quad (7)$$

where V_{IN} is the desired turn-on voltage.

The hysteresis voltage increases by the factor $(R_{EN1} + R_{EN2})/R_{EN2}$. For the example shown in Figure 45, the enable threshold is 3.6 V with a hysteresis of 300 mV.

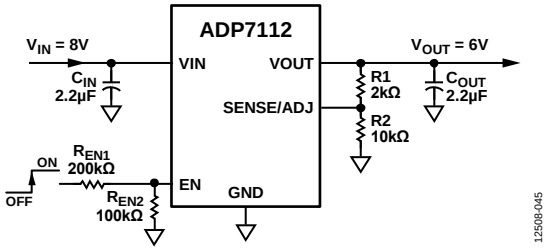

Figure 45. Typical EN Pin Voltage Divider

Figure 44 shows the typical hysteresis of the EN pin. This prevents on/off oscillations that can occur due to noise on the EN pin as it passes through the threshold points.

SOFT START

The ADP7112 uses an internal soft start (SS pin open) to limit the inrush current when the output is enabled. The start-up time for the 3.3 V option is approximately 380 µs from the time the EN active threshold is crossed to when the output reaches 90% of the final value. As shown in Figure 46, the start-up time is dependent on the output voltage setting.

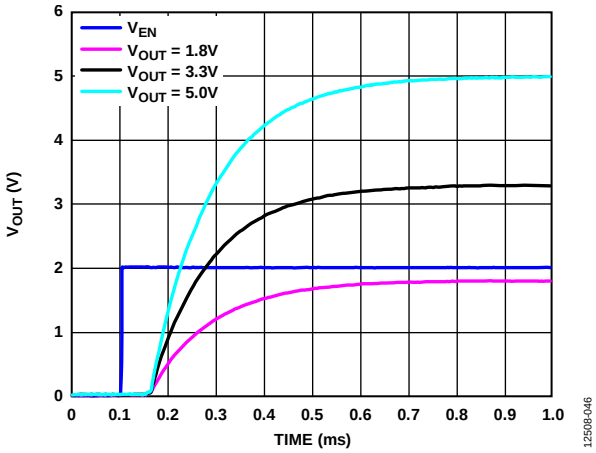

Figure 46. Typical Start-Up Behavior

An external capacitor connected to the SS pin determines the soft start time. This SS pin can be left open for a typical 380 µs start-up time. Do not ground this pin. When an external soft start capacitor (C_{SS}) is used, the soft start time is determined by the following equation:

$$SS_{TIME}\text{ (sec)} = t_{START\text{-}UP\ at\ 0\ pF} + (0.6 \times C_{SS})/I_{ss} \quad (8)$$

where:

$t_{START\text{-}UP\ at\ 0\ pF}$ is the start-up time at C_{SS} = 0 pF (typically 380 µs).
C_{SS} is the soft start capacitor (F).
I_{ss} is the soft start current (typically 1.15 µA).

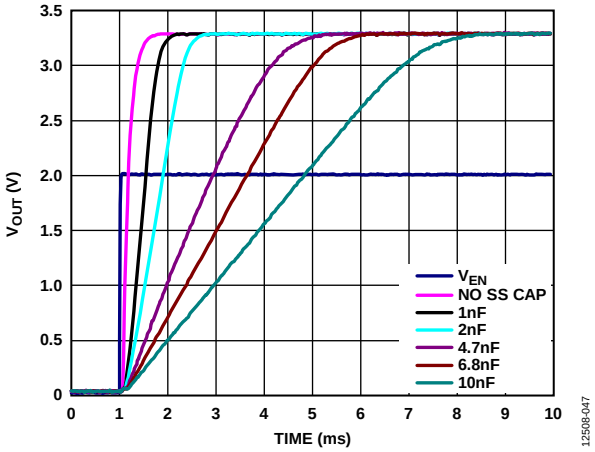

Figure 47. Typical Soft Start Behavior, Different C_{SS}

NOISE REDUCTION OF THE ADP7112 IN ADJUSTABLE MODE

The ultralow output noise of the ADP7112 is achieved by keeping the LDO error amplifier in unity gain and setting the reference voltage equal to the output voltage. This architecture does not work for an adjustable output voltage LDO in the conventional sense. However, the ADP7112 architecture allows any fixed output voltage to be set to a higher voltage with an external voltage divider. For example, a fixed 5 V output can be set to a 6 V output according to Equation 3 (see Figure 2).

$$V_{OUT} = 5\ V(1 + R1/R2)$$

The disadvantage in using the ADP7112 in this manner is that the output voltage noise is proportional to the output voltage. Therefore, it is best to choose a fixed output voltage that is close to the target voltage to minimize the increase in output noise.

The adjustable LDO circuit can be modified to reduce the output voltage noise to levels close to that of the fixed output ADP7112. The circuit shown in Figure 48 adds two additional components to the output voltage setting resistor divider. C_{NR} and R_{NR} are added in parallel with R1 to reduce the ac gain of the error amplifier. R_{NR} is chosen to be small with respect to R2. If R_{NR} is 1% to 10% of the value of R2, the minimum ac gain of the error amplifier is approximately 0.1 dB to 0.8 dB. The actual gain is determined by the parallel combination of R_{NR} and R1. This gain ensures that the error amplifier always operates at slightly greater than unity gain.

C_{NR} is chosen by setting the reactance of C_{NR} equal to R1 − R_{NR} at a frequency between 1 Hz and 50 Hz. This setting places the frequency where the ac gain of the error amplifier is 3 dB down from the dc gain.

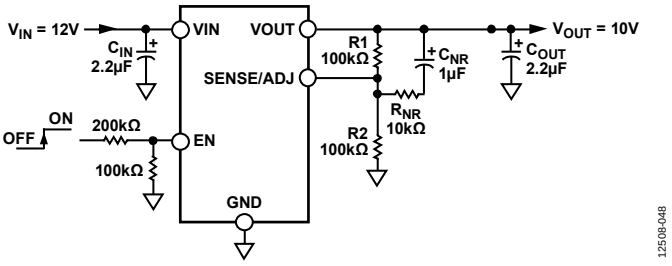

Figure 48. Noise Reduction Modification

The noise of the adjustable LDO is found by using the following formula, assuming the noise of a fixed output LDO is approximately 11 µV.

$$Noise = 11\ \mu V \times (R_{PAR} + R2)/R2 \quad (9)$$

where R_{PAR} is a parallel combination of $R1$ and R_{NR}.

Based on the component values shown in Figure 48, the ADP7112 has the following characteristics:

- DC gain of 2 (6 dB)
- 3 dB roll-off frequency of 1.59 Hz
- High frequency ac gain of 1.09 (0.75 dB)
- Noise reduction factor of 1.83 (5.25 dB)
- RMS noise of the adjustable LDO without noise reduction of 22 µV rms
- RMS noise of the adjustable LDO with noise reduction (assuming 11 µV rms for fixed voltage option) of 12 µV rms

CURRENT-LIMIT AND THERMAL OVERLOAD PROTECTION

The ADP7112 is protected against damage due to excessive power dissipation by current and thermal overload protection circuits. The ADP7112 is designed to current limit when the output load reaches 360 mA (typical). When the output load exceeds 360 mA, the output voltage is reduced to maintain a constant current limit.

Thermal overload protection is included, which limits the junction temperature to a maximum of 150°C (typical). Under extreme conditions (that is, high ambient temperature and/or high power dissipation) when the junction temperature starts to rise above 150°C, the output is turned off, reducing the output current to zero. When the junction temperature drops below 135°C, the output is turned on again, and output current is restored to the operating value.

Consider the case where a hard short from VOUT to ground occurs. At first, the ADP7112 current limits, so that only 360 mA is conducted into the short. If self heating of the junction is great enough to cause the temperature to rise above 150°C, thermal shutdown activates, turning off the output and reducing the output current to zero. As the junction temperature cools and drops below 135°C, the output turns on and conducts 360 mA into the short, again causing the junction temperature to rise above 150°C. This thermal oscillation between 135°C and 150°C causes a current oscillation between 360 mA and 0 mA that continues as long as the short remains at the output.

Current-limit and thermal limit protections protect the device against accidental overload conditions. For reliable operation, device power dissipation must be externally limited so that the junction temperature does not exceed 125°C.

EFFECT OF NOISE REDUCTION ON START-UP TIME

The start-up time of the ADM7172 is affected by the noise reduction network and must be considered in applications where power supply sequencing is critical.

The noise reduction circuit adds a pole in the feedback loop, slowing down the start-up time. The start-up time for an adjustable model with a noise reduction network can be approximated using the following equation:

$$SSNR_{TIME}\ (\text{sec}) = 5.5 \times C_{NR} \times (R_{NR} + R_1)$$

For a C_{NR}, R_{NR}, and R_1 combination of 1 µF, 10 kΩ, and 100 kΩ as shown in Figure 48, the start-up time is approximately 0.6 sec. When $SSNR_{TIME}$ is greater than SS_{TIME}, $SSNR_{TIME}$ dictates the length of the start-up time instead of the soft start capacitor.

THERMAL CONSIDERATIONS

In applications with a low input-to-output voltage differential, the ADP7112 does not dissipate much heat. However, in applications with high ambient temperature and/or high input voltage, the heat dissipated in the package can become large enough to cause the junction temperature of the die to exceed the maximum junction temperature of 125°C.

When the junction temperature exceeds 150°C, the converter enters thermal shutdown. It recovers only after the junction temperature has decreased below 135°C to prevent any permanent damage. Therefore, thermal analysis for the chosen application is very important to guarantee reliable performance over all conditions. The junction temperature of the die is the sum of the ambient temperature of the environment and the temperature rise of the package due to the power dissipation, as shown in Equation 1.

To guarantee reliable operation, the junction temperature of the ADP7112 must not exceed 125°C. To ensure that the junction temperature stays below this maximum value, the user must be aware of the parameters that contribute to junction temperature changes. These parameters include ambient temperature, power dissipation in the power device, and thermal resistances between the junction and ambient air (θ_{JA}). The θ_{JA} number is dependent on the package assembly compounds that are used and the amount of copper solders the package GND pin to the PCB.

Table 6 shows typical θ_{JA} values of the 6-ball WLCSP package for various PCB copper sizes. The typical Ψ_{JB} value for the 6-ball WLCSP package is 58°C/W.

Table 6. Typical θ_{JA} Values

Copper Size (mm)	θ_{JA} (°C/W) for WLCSP
25[1]	260
50	159
100	157
500	151

[1] Device soldered to minimum size pin traces.

To calculate the junction temperature of the ADP7112, use Equation 1.

$$T_J = T_A + (P_D \times \theta_{JA})$$

where:
T_A is the ambient temperature.
P_D is the power dissipation in the die, given by

$$P_D = ((V_{IN} - V_{OUT}) \times I_{LOAD}) + (V_{IN} \times I_{GND}) \quad (10)$$

where:
V_{IN} and V_{OUT} are input and output voltages, respectively.
I_{LOAD} is the load current.
I_{GND} is the ground current.

Power dissipation due to ground current is quite small and can be ignored. Therefore, the junction temperature equation simplifies to the following:

$$T_J = T_A + (((V_{IN} - V_{OUT}) \times I_{LOAD}) \times \theta_{JA}) \quad (11)$$

As shown in Equation 4, for a given ambient temperature, input-to-output voltage differential, and continuous load current, there exists a minimum copper size requirement for the PCB to ensure that the junction temperature does not rise above 125°C. Figure 49 to Figure 51 show junction temperature calculations for different ambient temperatures, power dissipation, and areas of PCB copper.

In the case where the board temperature is known, use the thermal characterization parameter, Ψ_{JB}, to estimate the junction temperature rise (see Figure 52). Calculate the maximum junction temperature by using Equation 2.

$$T_J = T_B + (P_D \times \Psi_{JB})$$

The typical value of Ψ_{JB} is 58°C/W for the 6-ball WLCSP package.

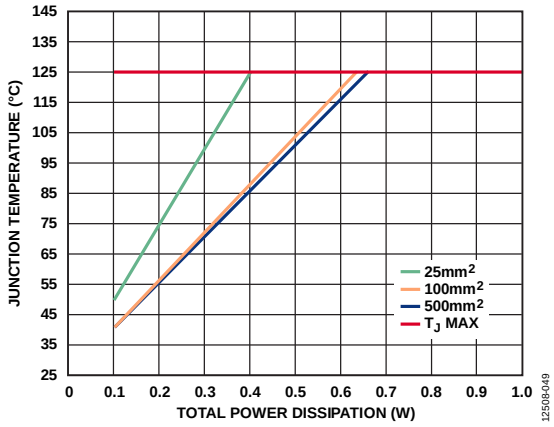

Figure 49. WLCSP, T_A = 25°C

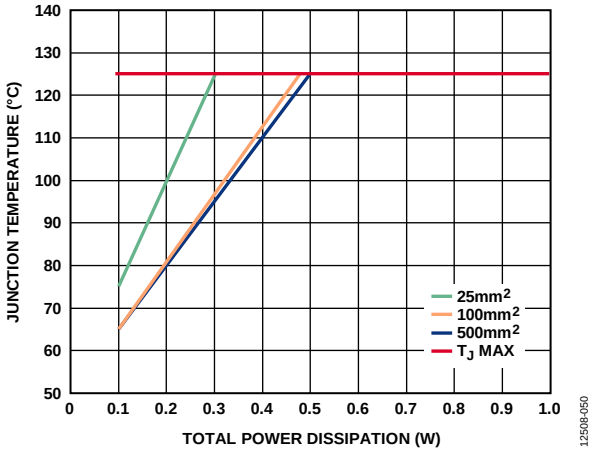

Figure 50. WLCSP, T_A = 50°C

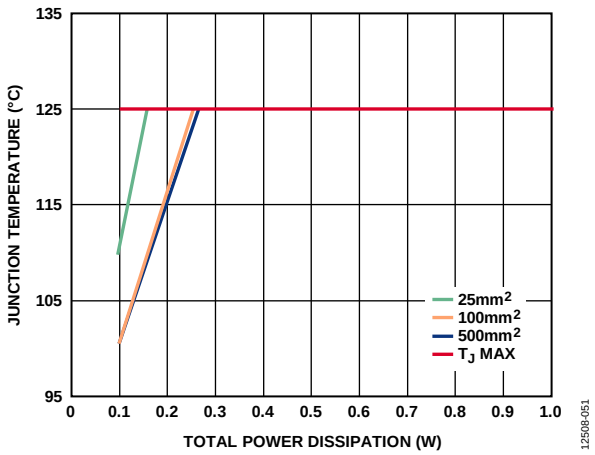

Figure 51. WLCSP, $T_A = 85°C$

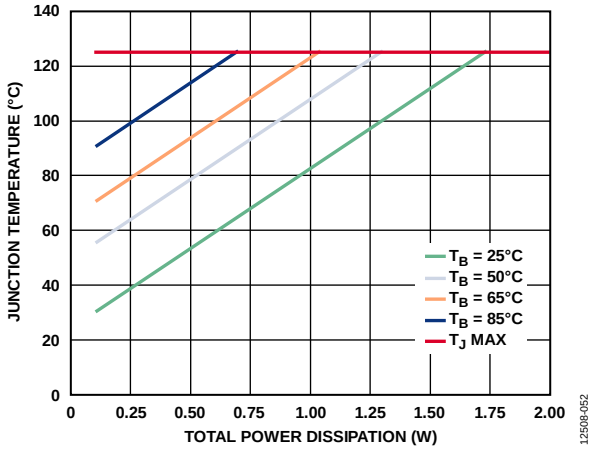

Figure 52. WLCSP Junction Temperature Rise, Different Board Temperatures

PCB LAYOUT CONSIDERATIONS

Heat dissipation from the package can be improved by increasing the amount of copper attached to the pins of the ADP7112. However, as listed in Table 6, a point of diminishing returns is eventually reached, beyond which an increase in the copper size does not yield significant heat dissipation benefits.

Place the input capacitor as close as possible to the VIN and GND pins. Place the output capacitor as close as possible to the VOUT and GND pins. Use of 0805 or 1206 size capacitors and resistors achieves the smallest possible footprint solution on boards where area is limited.

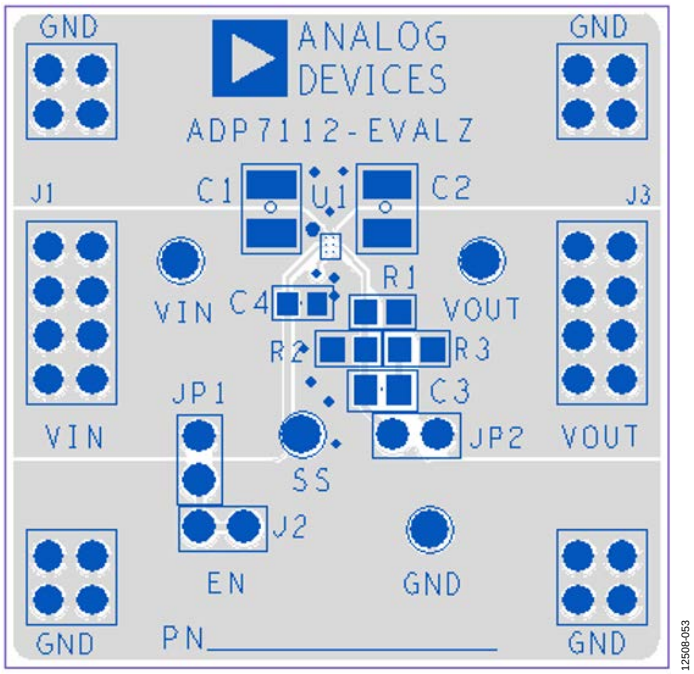

Figure 53. Example WLCSP PCB Layout

Table 7. Recommended LDOs for Super Low Noise Operation

Device Number	V_{IN} Range (V)	V_{OUT} Fixed (V)	V_{OUT} Adjust (V)	I_{OUT} (mA)	I_Q at I_{OUT} (µA)	I_{GND-SD} Max (µA)	Soft Start	P_{GOOD}	Noise (Fixed) 10 Hz to 100 kHz (µV rms)	PSRR 100 kHz (dB)	PSRR 1 MHz (dB)	Package
ADP7102	3.3 to 20	1.5 to 9	1.22 to 19	300	750	75	No	Yes	15	60	40	3 mm × 3 mm 8-lead LFCSP, 8-lead SOIC
ADP7104	3.3 to 20	1.5 to 9	1.22 to 19	500	900	75	No	Yes	15	60	40	3 mm × 3 mm 8-lead LFCSP, 8-lead SOIC
ADP7105	3.3 to 20	1.8, 3.3, 5	1.22 to 19	500	900	75	Yes	Yes	15	60	40	3 mm × 3 mm 8-lead LFCSP, 8-lead SOIC
ADP7112	2.7 to 20	1.2 to 5	1.2 to 19	200	160	10	Yes	No	11	68	50	1 mm × 1.2 mm 6-ball WLCSP
ADP7118	2.7 to 20	1.2 to 5	1.2 to 19	200	160	10	Yes	No	11	68	50	2 mm × 2 mm 6-lead LFCSP, 8-lead SOIC, 5-lead TSOT
ADP7142	2.7 to 40	1.2 to 5	1.2 to 39	200	160	10	Yes	No	11	68	50	2 mm × 2 mm 6-lead LFCSP, 8-lead SOIC, 5-lead TSOT
ADP7182	−2.7 to −28	−1.8 to −5	−1.22 to −27	−200	−650	−8	No	No	18	45	45	2 mm × 2 mm 6-lead LFCSP, 3 × 3 mm 8-lead LFCSP, 5-lead TSOT

Table 8. Related Devices

Model	Input Voltage (V)	Output Current (mA)	Package
ADP7118ACP	2.7 to 20	200	6-lead LFCSP
ADP7118ARD	2.7 to 20	200	8-lead SOIC
ADP7118AUJ	2.7 to 20	200	5-lead TSOT
ADP7142ACP	2.7 to 40	200	6-lead LFCSP
ADP7142ARD	2.7 to 40	200	8-lead SOIC
ADP7142AUJ	2.7 to 40	200	5-lead TSOT

OUTLINE DIMENSIONS

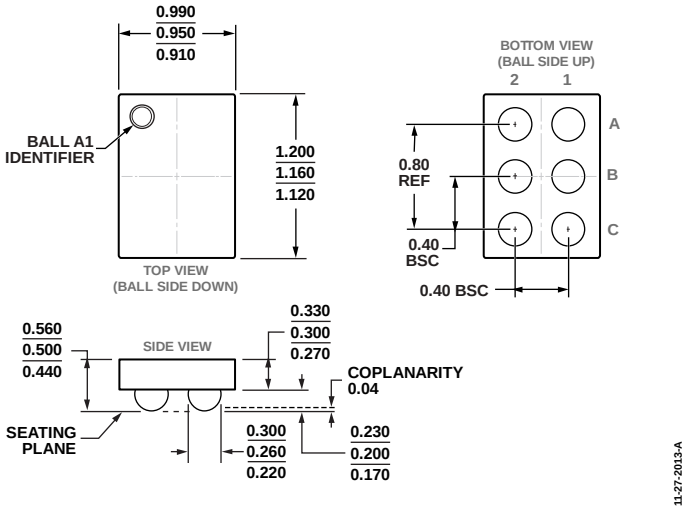

Figure 54. 6-Ball Wafer Level Chip Scale Package [WLCSP]
1.00 mm × 1.20 mm Body
(CB-6-15)
Dimensions shown in millimeters

ORDERING GUIDE

Model[1]	Temperature Range	Output Voltage (V)[2, 3]	Package Description	Package Option	Branding
ADP7112ACBZ-1.2-R7	−40°C to +125°C	Adjustable (1.2)	6-Ball WLCSP	CB-6-15	CQ
ADP7112ACBZ-1.8-R7	−40°C to +125°C	1.8	6-Ball WLCSP	CB-6-15	CR
ADP7112ACBZ-2.5-R7	−40°C to +125°C	2.5	6-Ball WLCSP	CB-6-15	CS
ADP7112ACBZ-3.3-R7	−40°C to +125°C	3.3	6-Ball WLCSP	CB-6-15	CT
ADP7112ACBZ-5.0-R7	−40°C to +125°C	5.0	6-Ball WLCSP	CB-6-15	CU
ADP7112CB-EVALZ		3.3	WLCSP Evaluation Board		

[1] Z = RoHS Compliant Part.
[2] For additional voltage options, contact a local Analog Devices, Inc., sales or distribution representative.
[3] The evaluation boards are preconfigured with an adjustable ADP7112.